1.0 General Description

The G5237FT is a high performance AC/DC power supply controller which uses digital control technology to build peak current mode PWM flyback power supplies. The device operates in quasi-resonant mode to provide high efficiency along with a number of key built-in protection features while minimizing the external component count, simplifying EMI design and lowering the total bill of material cost.The G5237FT removes the need for secondary feedback circuit while achieving excellent line and load regulation. It also eliminates the need for loop compensation components while maintaining stability over all operating conditions. Pulse-by-pulse waveform analysis allows for a loop response that is much faster than traditional solutions, resulting in improved dynamic load response for both one-time and repetitive load transients. GlobalSemi's innovative proprietary technology ensures that power supplies built with the G5237FT can achieve both highest average active efficiency and have fast dynamic load response in a compact form factor in typical applications.

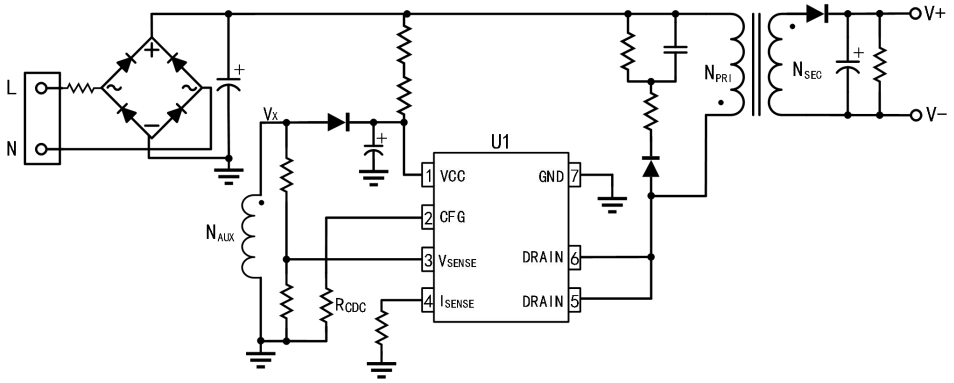
Features

- ◆Built-in 650V Power Mosfet
- ◆No-load power consumption < 75 mW at 230 VAC along with fast dynamic load response
- ◆Tight constant-voltage and constant current regulation across line and load range
- ◆Primary-side feedback eliminates opto-isolators and simplifies design
- ◆Proprietary optimized 90 kHz maximum PWM switching frequency with quasi-resonant operation achieves best size, efficiency and common mode noise
- ◆Adaptive Multi-mode PWM/PFM control improves efficiency
- ◆No external loop compensation components required
- ◆User-configurable 5-level cable drop
- ◆Complies with EPA 2.0 energy-efficiency specifications with ample margin
- ◆Built-in: output SCP, output OVP, OCP, current-sense-resistor fault protection .
- ◆No audible noise over entire operating range

Applications

- Compact AC/DC adapter/chargers for media tablets and smart phones
- AC/DC adapters for consumer electronics

TYPICAL Application



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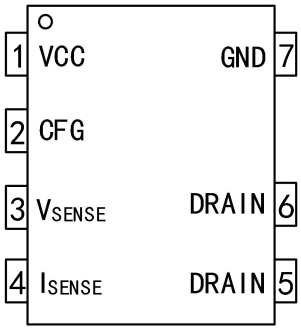
2.0 Products Information

2.1 Pin configuration

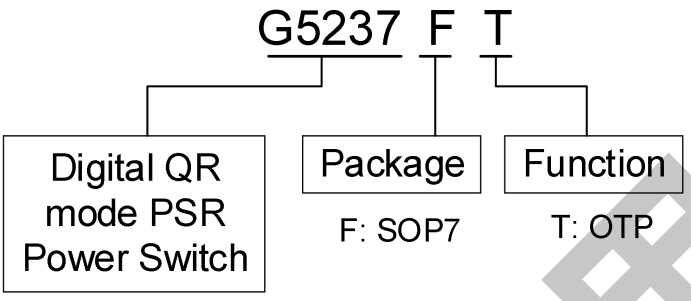


G5237FT(SOP7)

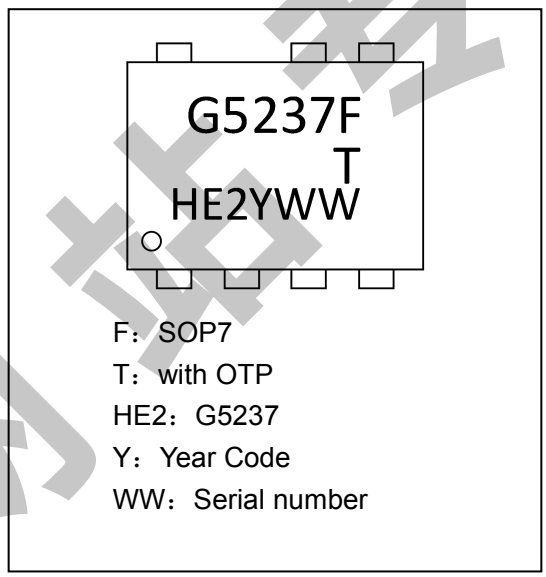
Name	Pin	I/O	Description
VCC	1	Power Input	Power supply for the controller during normal operation. The controller will start up when VCC reaches 14.0 V (typical) and will shut down when the VCC voltage drops below 6.5 V (typical). A decoupling capacitor of 0.1 μF or so should be connected between the VCC pin and GND.
CFG	2	Analog Input	Used to configure external cable drop compensation (CDC) at the beginning of start-up and provide accurate over-voltage protection during normal operation by sensing output voltage via auxiliary winding.
V_{SENSE}	3	Analog Input	Sense signal input from auxiliary winding. This provides the secondary voltage feedback used for output regulation..
I_{SENSE}	4	Analog Input	Primary current sense. Used for cycle-by-cycle peak current control and limit.
DRAIN	5/6	Output	HV MOSFET Drain Pin.The Drain pin is connected to the primary lead of the transformer
GND	7	Ground	Ground.

2.2 Ordering Information

Part Number	Marking ID	Package	Packing
G5237F-T	G5237F-T	SOP7	4000/Tape&Reel



2.3 Marking Information



Year Code

A	B	C	D	E	F	G	H	I	J	K	L	M
2013	2014	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
N	O	P	Q	R	S	T	U	V	W	X	Y	Z
2026	2027	2028	2029	2030	2031	2032	2033	2034	2035	2036	2037	2038

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3.0 Block diagrams

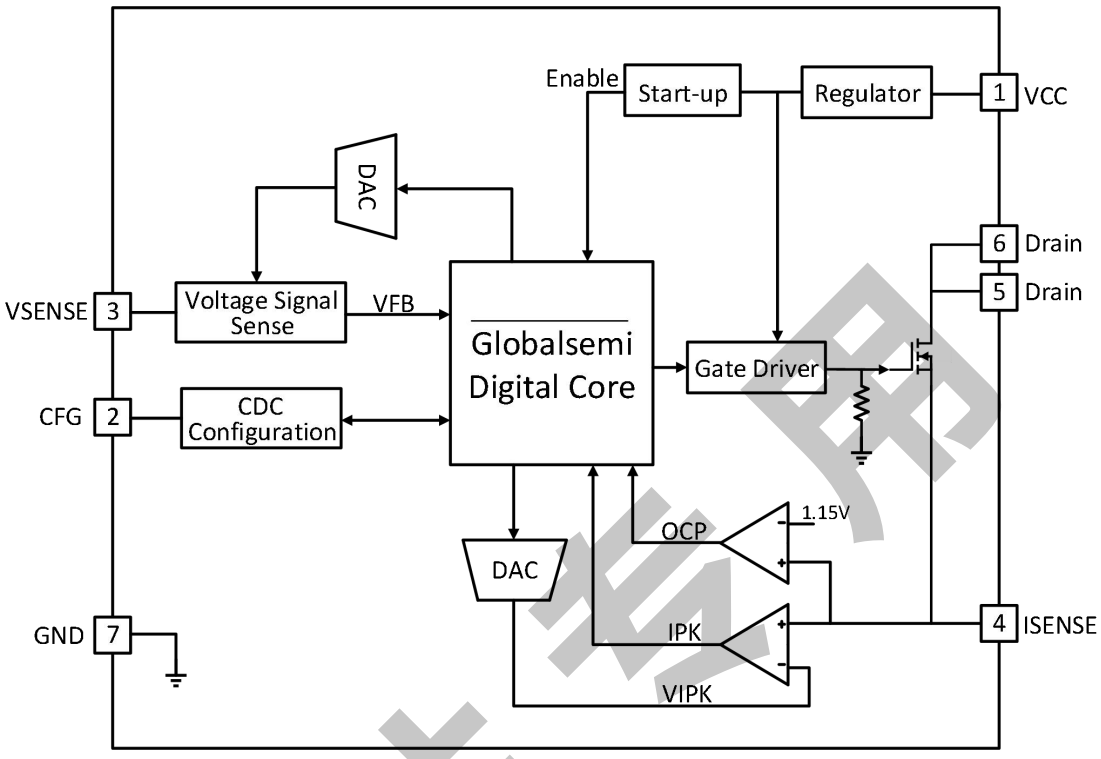

Figure3.1 G5237FT Functional Block Diagram

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4.0 Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Drain Voltage（off state）	V_{DRAIN}	-0.3toBVdss	V
Continuous Drain Current at Tc=25℃	$I_{D(DC)}$	2	A
Continuous Drain Current at Tc=100℃	$I_{D(DC)}$	1.25	A
Pulsed Drain Current note1	$I_{DM(pluse)}$	8	A
DC supply voltage range (pin 1, I_{DD} = 20mA max)	V_{CC}	-0.3 to 25.0	V
Continuous DC supply current at VCC pin (VCC = 15 V)	I_{DD}	20	mA
CFG(Pin 2, I_{CFG} ≤ 20mA)		-0.8 to 4.0	V
V_{SENSE} input (Pin 3, I_{VENSE} ≤ 10mA)		-0.7 to 4.0	V
I_{SENSE} input (Pin 4)		-0.3 to 4.0	V
Maximum junction temperature	T_{JMAX}	150	℃
Operating junction temperature	T_{JOPT}	-20 to 150	℃
Storage temperature	T_{STG}	–65 to 150	℃
Lead temperature during IR reflow for ≤ 15 seconds	T_{LEAD}	260	℃
Thermal resistance junction-to-ambient	$R_{\theta-JA}$	75	℃/W
Thermal resistance junction-to-case	$R_{\theta-JC}$	32	℃/W
ESD rating per JEDEC JESD22-A114		2,000	V
Latch-up test per JEDEC 78		±100	mA

Note1：Repetitive Rating：Pulse width limited by maximum junction temperature

4.1 Recommended Operating Condition

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
VCC SECTION						
VCC	Operating voltage		7		15	V

5.0 Electrical Characteristics

(TA = 25℃, VCC=12V, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
VCC SECTION						
$VCC_{(MAX)}$	Maximum operating voltage	(Note 2)	-	-	20	V
$VCC_{(ST)}$	Start-up threshold	VCC rising	13.0	14.0	15.0	V
$VCC_{(UVL)}$	UVLO threshold	VCC falling	6.2	6.5	6.8	V
$VCC_{(RLS)}$	Latch release threshold	VCC falling	4.2	4.5	4.8	V
$I_{IN(ST)}$	Start-up current	VCC = 12V	-	7.8	-	uA
I_{CCQ}	Quiescent current	C_L=330pF,V_{SENSE}=1.5V	-	3.5	-	mA
V_{SENSE} SECTION						
I_{BVS}	Input leakage current	V_{SENSE} = 2 V	-	-	1	uA
$V_{SENSE(NOM)}$	Nominal voltage threshold		1.521	1.536	1.551	V
$V_{SENSE(MAX)}$	V_{SENSE}-based output OVP threshold with no CDC	Note1	-	1.838	-	V
I_{SENSE} SECTION						
V_{OCP}	Over-current threshold	-	1.11	1.15	1.19	V
$V_{IPK(HIGH)}$	I_{SENSE} regulation upper limit	Note 2	-	1.0	-	V
$V_{IPK(LOW)}$	ISENSE regulation lower limit	Note 2	-	0.23	-	V
CFG Section						
$V_{SD-TH(R)}$	OVP shutdown threshold	rising edge	0.96	1.015	1.07	V
R_{CFG}	Resistance between CFG and GND			9.5		kΩ
Frequency SECTION						
f_{SW}	Switching frequency	>50% load		90		kHz
Thermal Characteristics						
TSD	OTP shutdown Threshold			140		℃
TSD-R	OTP shutdown recovery			110		℃
MOSFET SECTION						
BVdss	Drain-Source Breakdown Voltage		650			V
Rdson	Static drain to source on resistance			2.4		Ω

Note 1: The V_{SENSE}-based output OVP threshold depends on the CDC setup, see Section 7.10 for more details. Note 2: These parameters are not 100% tested, guaranteed by design and characterization.
Note 3: Operating frequency varies based on the load conditions.

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6. Typical Performance Characteristics

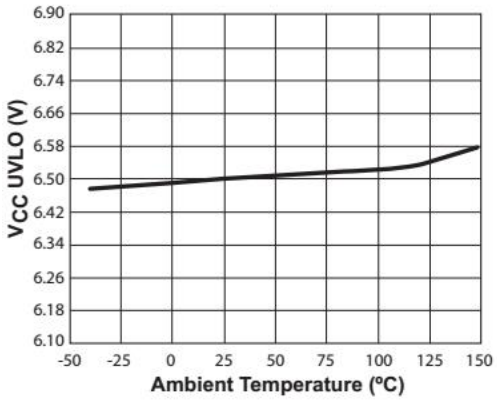

Figure 6.1 VCC UVLO vs. Temperature

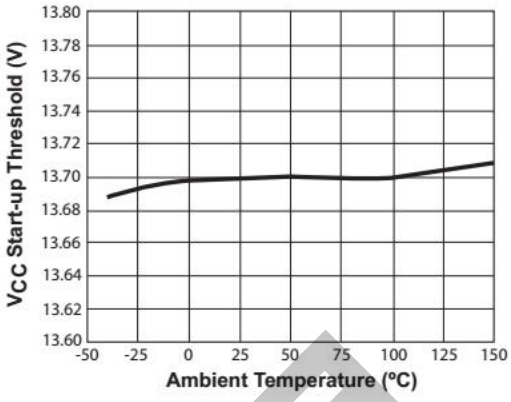

Figure 6.2 Start-Up Threshold vs. Temperature

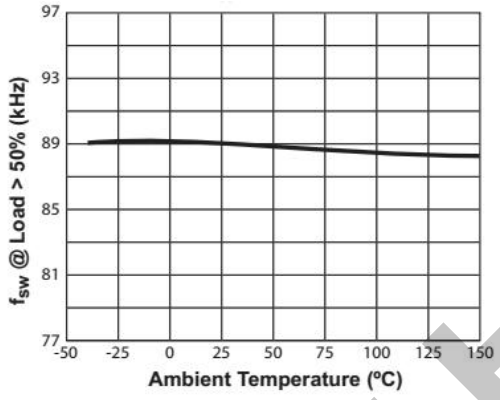

Figure 6.3 Switching Frequency vs. Temperature

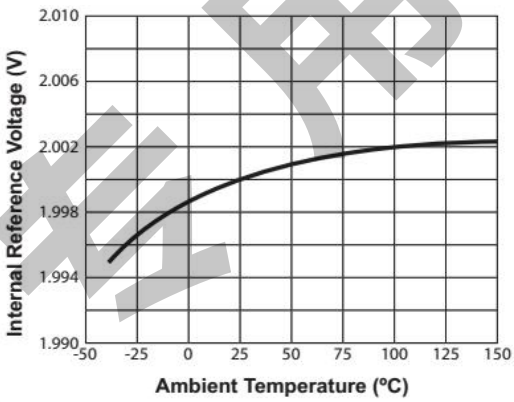

Figure 6.4 Internal Reference vs. Temperature

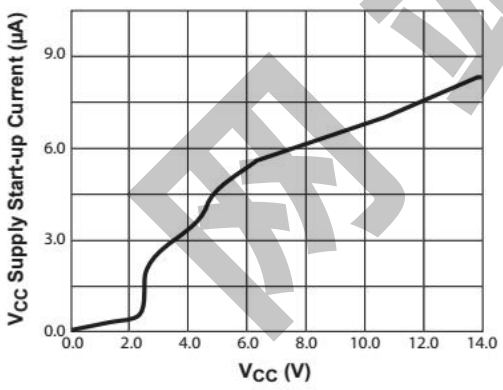

Figure 6.5 VCC vs. VCC Supply Start-up Current

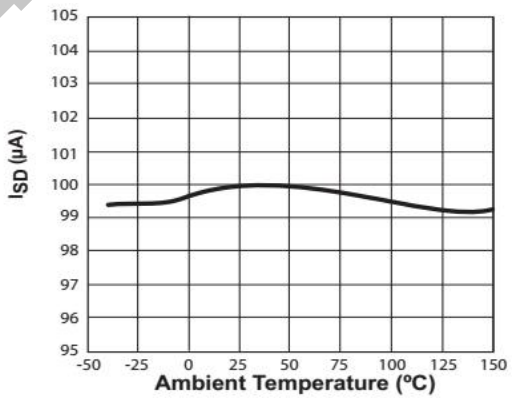

Figure 6.6 I_{SD} vs. Temperature

Notes:

Note1: Operating frequency varies based on the load conditions, see Section 7.6 for more details.

7. Theory of Operation

The G5237FT is a digital power switch which uses a new, proprietary primary-side control technology to eliminate the opto-isolated feedback and secondary regulation circuits required in traditional designs. This results in a low-cost solution for low power AC/DC adapters. The core PWM processor uses fixed-frequency Discontinuous Conduction Mode (DCM) operation at higher power levels and switches to variable frequency operation at light loads to maximize efficiency. Furthermore, GlobalSemi's digital control technology enables fast dynamic response, tight output regulation, and full featured circuit protection with primary-side control.

Referring to the block diagram in Figure 2.1, the G5237FT operates in peak current mode control. The digital logic control block generates the switching on-time and off-time information based on the output voltage and current feedback signal and provides commands to dynamically control the external MOSFET gate voltage. The I_{SENSE} is an analog input configured to sense the primary current in a voltage form. In order to achieve the peak current mode control and cycle-by-cycle current limit, the V_{IPK} sets the threshold for the I_{SENSE} to compare with, and it varies in the range of 0.23 V (typical) to 1.00 V (typical) under different line and load conditions. The system loop is automatically compensated internally by a digital error amplifier. Adequate system phase margin and gain margin are guaranteed by design and no external analog components are required for loop compensation. The G5237FT uses an advanced digital control algorithm to reduce system design time and increase reliability.

Furthermore, accurate secondary constant current operation is achieved without the need for any secondary-side sense and control circuits.
The G5237FT uses adaptive Multi-mode PWM/PFM control to dynamically change the MOSFET switching frequency for efficiency,EMI,and power consumption optimization. In addition, it achieves unique MOSFET quasi-resonant switching to further improve efficiency and reduce EMI. Built-in single-point fault protection features include over-voltage protection (OVP), output short-circuit protection (SCP), over-current protection (OCP), and I_{SENSE} fault detection.

GlobalSemi's digital control scheme is specifically designed to address the challenges and trade-offs of power conversion design.This innovative technology is ideal for balancing new regulatory requirements for green mode operation with more practical design considerations such as lowest possible cost, smallest size and high performance output control.

7.1 Start-up and Soft-start

When the VCC bypass capacitor is charged to a voltage higher than the start-up threshold $VCC_{(ST)}$, the ENABLE signal becomes active and the G5237FT begins to perform initial OTP check, followed by CDC configuration. Afterwards, the G5237FT commences soft-start function. During this start-up process an adaptive soft-start control algorithm is applied, where the initial output pulses will be small and gradually get larger until the full pulse width is achieved. The peak current is limited cycle by cycle by the I_{PEAK} comparator.If at any time the VCC voltage drops below under-voltage lockout (UVLO) threshold $VCC_{(UVL)}$ then the G5237FT goes to shutdown. At this time ENABLE signal becomes low and the VCC capacitor begins to charge up again towards the start-up threshold to initiate a new soft-start process.

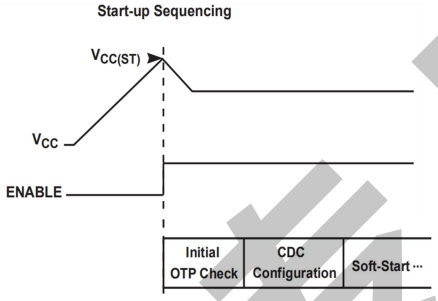

Figure 7.1: Start-up Sequencing Diagram

7.2 Understanding Primary Feedback

Figure 7.2 illustrates a simplified flyback converter. When the switch Q1 conducts during $t_{ON}(t)$, the current $i_g(t)$ is directly drawn from rectified sinusoid $v_g(t)$. The energy $E_g(t)$ is stored in the magnetizing inductance L_M.The rectifying diode D1 is reverse biased and the load current I_O is supplied by secondary capacitor C_O. When Q1 turns off, D1 conducts and the stored energy $E_g(t)$ is delivered to the output.

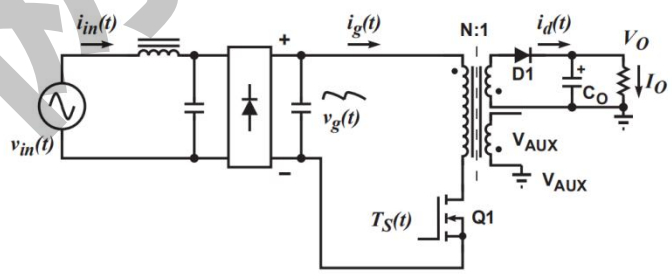

Figure 7.2: Simplified Flyback Converter

In order to tightly regulate the output voltage, the information about the output voltage and load current need to be accurately sensed. In the DCM flyback converter, this information can be read via the auxiliary winding or the primary magnetizing inductance (L_M). During the Q1 on-time, the load current is supplied from the output filter capacitor

C_O. The voltage across L_M is $v_g(t)$, assuming the voltage dropped across Q1 is zero. The current in Q1 ramps up linearly at a rate of:

$$\frac{di_g(t)}{dt} = \frac{v_g(t)}{L_M} \quad (7.1)$$

At the end of on-time, the current has ramped up to:

$$i_{g\_peak}(t) = \frac{v_g(t) \times t_{ON}}{L_M} \quad (7.2)$$

This current represents a stored energy of:

$$E_g = \frac{L_M}{2} \times i_{g\_peak}(t)^2 \quad (7.3)$$

When Q1 turns off at t_o, $i_g(t)$ in L_M forces a reversal of polarities on all windings. Ignoring the communication-time caused by the leakage inductance L_K at the instant of turn-off t_o, the primary current transfers to the secondary at a peak amplitude of:

$$i_d(t) = \frac{N_P}{N_S} \times i_{g\_peak}(t) \quad (7.4)$$

Assuming the secondary winding is master, and the auxiliary winding is slave,

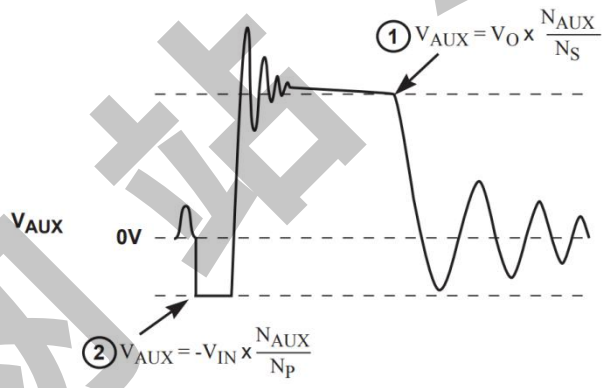

Figure 7.3: Auxiliary Voltage Waveforms

The auxiliary voltage is given by:

$$V_{AUX} = \frac{N_{AUX}}{N_S}(V_O + \Delta V) \quad (7.5)$$

and reflects the output voltage as shown in Figure 7.3.

The voltage at the load differs from the secondary voltage by a diode drop and IR losses. Thus, if the secondary voltage is always read at a constant secondary current, the difference between the output voltage and the secondary voltage will be a fixed ΔV. Furthermore, if the voltage can be read when the secondary current is small, ΔV will also be small. With the G5237FT, ΔV can be ignored.

The real-time waveform analyzer in the G5237FT reads this information cycle by cycle. The part then generates a feedback voltage V_{FB}. The V_{FB} signal precisely represents the output voltage under most conditions and is used to regulate the output voltage.

7.3 Constant Voltage Operation

After soft-start has been completed, the digital control block measures the output conditions. It determines output power levels and adjusts the control system according to a light load or heavy load. If this is in the normal range, the device operates in the Constant Voltage (CV) mode, and changes the pulse width (T_{ON}) and off time (T_{OFF}) in order to meet the output voltage regulation requirements.

If no voltage is detected on V_{SENSE} it is assumed that the auxiliary winding of the transformer is either open or shorted and the G5237FT shuts down.

7.4 Constant Current Operation

The constant current (CC) mode is useful in battery charging applications.During this mode of operation the G5237FT will regulate the output current at a constant level regardless of the output voltage, while avoiding continuous conduction mode.To achieve this regulation the G5237FT senses the load current indirectly through the primary current. The primary current is detected by the I_{SENSE} pin through a resistor from the MOSFET source to ground.

The G5237FT also provides a product option to disable the CC mode operation. If the power supply enters into the CC mode during normal operation, this product option will shut down the power supply. This feature serves as an over-load protection and can be used in certain adapter applications.

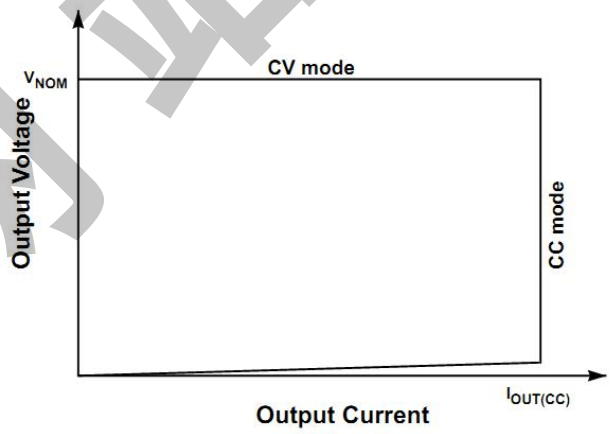

Figure 7.4: Power Envelope

7.5 Multi-Mode PWM/PFM Control and Quasi-Resonant Switching

The G5237FT uses a proprietary adaptive Multi-mode PWM /PFM control to dramatically improve the light-load efficiency and thus the overall average efficiency.

During the constant voltage (CV) operation, the G5237FT normally operates in a

pulse-width-modulation (PWM) mode during heavy load conditions. In the PWM mode, the switching frequency keeps around constant. As the output load I_{OUT} is reduced, the on-time T_{ON} is decreased, and the controller adaptively transitions to a pulse-frequency-modulation (PFM) mode. During the PFM mode, the MOSFET is turned on for a set duration under a given instantaneous rectified AC input voltage, but its off time is modulated by the load current. With a decreasing load current, the off time increases and thus the switching frequency decreases.

When the switching frequency approaches to human ear audio band, the G5237FT Transitions to a second level of PWM mode, namely Deep PWM mode (DPWM). During the DPWM mode, the switching frequency keeps around 25 kHz in order to avoid audible noise. As the load current is further reduced, the G5237FT transitions to a second level of PFM mode, namely Deep PFM mode (DPFM), which can reduce the switching frequency to a very low level. Although the switching frequency drops across the audible frequency range during the DPFM mode, the output current in the power converter has reduced to an insignificant level in the DPWM mode before transitioning to the DPFM mode. Therefore, the power converter practically produces no audible noise, while achieving high efficiency across varying load conditions.
As the load current reduces to very low or no-load condition, the G5237FT transitions from the DPFM to the third level of PWM mode, namely Deep-Deep PWM mode (DDPWM), where the switching frequency is fixed at around 1.8 kHz. The G5237FT also incorporates a unique proprietary quasi-resonant switching scheme that achieves valley-mode turn on for every PWM/PFM switching cycle, during all PFM and PWM modes and in both CV and CC operations.This unique feature greatly reduces the switching loss and dv/dt across the entire operating range of the power supply.Due to the nature of quasi-resonant switching, the actual switching frequency can vary slightly cycle by cycle, providing the additional benefit of reducing EMI. Together these innovative digital control architecture and algorithms enable the G5237FT to achieve highest overall efficiency and lowest EMI, without causing audible noise over entire operating range.

7.6 Variable Frequency Operation Mode

At each of the switching cycles, the falling edge of V_{SENSE} will be checked. If the falling edge of V_{SENSE} is not detected, the off-time will be extended until the falling edge of V_{SENSE} is detected. The maximum allowed transformer reset time is 110 μs. When the transformer reset time reaches 110 μs, the G5237FT shuts off.

7.7 Internal Loop Compensation

The G5237FT incorporates an internal Digital Error Amplifier with no requirement for external loop compensation. For a typical power supply design, the loop stability is guaranteed to provide at least 45 degrees of phase margin and -20 dB of gain margin.

7.8 Voltage Protection Features

The secondary maximum output DC voltage is limited by the G5237FT. When the V_{SENSE} signal exceeds the output OVP threshold at point 1 indicated in Figure 7.3 the G5237FT shuts down.

Although there is no pin available to directly sense the input voltage, the G5237FT uses an innovative proprietary digital control method to detect and analyze the switch ON time, which provides real-time indirect sensing and monitoring of the magnitude and shape of the DC bulk capacitor voltage. This enables the G5237FT to determine and distinguish various conditions of the AC input voltage such as brown-out, brown-in and unplug, and to take appropriate actions. When the AC input voltage drops to below normal operation range and the power supply input is still connected to the AC source, the G5237FT initiates brown-out protection and shuts down the power supply adaptively according to the power supply load condition. Meanwhile, a brown-in input voltage threshold is set with hysteresis. In the case of the power supply input being unplugged or disconnected from the AC source, the G5237FT continues to control the switching actions to discharge the DC bulk capacitor voltage to a safe level before shutting down the power supply. Also, the G5237FT monitors the voltage on the VCC pin, and the IC shuts down immediately when the voltage on this pin is below the UVLO threshold.

When any of these faults are met the IC remains biased to discharge the VCC supply. Once VCC drops below UVLO threshold, the controller resets itself and then initiates a new soft-start cycle. The controller continues attempting start-up until the fault condition is removed.

7.9 PCL, OCP and SRS Protection

Peak-current limit (PCL), over-current protection (OCP) or FastOCP and sense-resistor -short protection (SRSP) are features built-in to the G5237FT.With the I_{SENSE} pin the G5237FT is able to monitor the peak primary current.This allows for cycle-by-cycle peak current control and limit.When the peak primary current multiplied by the I_{SENSE} resistor is greater than 1.15 V,over-current is detected and the IC will immediately turn off the gate driver until the next cycle.The output driver will send out a switching pulse in the next cycle, and the switching pulse will continue if the OCP threshold is not reached; or, the switching pulse will turn off again if the OCP threshold is reached.If the OCP occurs for several consecutive switching cycles, the G5237FT shuts down.

If the I_{SENSE} resistor is shorted there is a potential danger that over-current condition may not be detected. Thus, the IC is designed to detect this sense-resistor-short fault after start-up and shut down immediately.The VCC will be discharged since the IC remains biased. Once VCC drops below the UVLO threshold, the controller resets itself and then initiates a new soft-start cycle. The controller continues attempting to startup, but does not fully start-up until the fault condition is removed.

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7.10 CDC Configuration

The G5237FT incorporates an innovative approach to allow users to configure cable drop compensation (CDC) externally.This configuration is only performed once.It is completed after the initial OTP check but before the soft-start commences. During the CDC configuration, the internal digital control block senses the external resistance value between the CFG pin and ground, and then sets a corresponding CDC level to allow the device to compensate for IR drop in the secondary circuitry during normal operation.

Figure 4.1 shows a simple circuit to set CDC level by connecting a resistor, R_{CDC}, from the CFG pin to ground. The G5237FT provides five levels of CDC configurations: 0, 75 mV, 150 mV, 300 mV, and 450 mV. Table 7.1 below shows the resistance range for each of the five CDC levels. In practice, it is recommended to select resistance in the middle of the range wherever possible.
The “Cable Comp” specified in Table 7.1 refers to the voltage increment at PCB end from no-load to full-load conditions in the CV mode, with the assumption that the secondary diode voltage drop can be ignored at the point when the secondary voltage is sensed. Also, the “Cable Comp” is specified based on the nominal output voltage of 5 V. For different output voltage, the actual voltage increment needs to be scaled accordingly. For example,for 12V,the corresponding five levels of CDC configurations would be: 0,180mV, 360mV, 720mV, and 1080 mV.

To calculate the amount of cable compensation needed, take the resistance of the cable and connector and multiply by the maximum output current.
For each of the CDC levels, the internal V_{SENSE}-based OVP thresholds are different. Table 7.1 also lists the typical OVP thresholds for each CDC level.

Table7.1 Recommended resistance range and corresponding CDC levels for 5V output

CDC Level	1	2	3	4	5
R_{CDC} Range（kΩ）	0-2.70	3.5 – 4.5	6.00 – 8.00	13.00–16.50	60.00-NC
Cable Comp（mV）	0	75	150	300	450
V_{SENSE}-based OVP Threshold	1.838	1.861	1.884	1.930	1.976

7.11 External CFG-Based Accurate OVP

In the G5237FT, the CFG pin can also be used to provide the external over-voltage protection (OVP) besides fulfilling the CDC configuration. This external CFG-based OVP serves as a supplemental or extra protection in addition to the V_{SENSE}-based OVP. The circuit implementation can be found in Figure 7.5, where two resistors Ru and Rd form a

voltage divider to sense output voltage via auxiliary winding, with the tapping point

connected to the CFG pin. During the CDC configuration the G5237FT does not send out any drive signal at OUTPUT pin, and the switch Q1 remains in off-state. The resistors R1 and R2 are essentially connected in parallel since the bias winding is virtually shorted. Consequently, the paralleled resistance of Ru and Rd sets the CDC level. Meanwhile, during normal operation, the CFG pin reflects output voltage in real-time, in the similar fashion as the V_{SENSE} does at point 1 in Figure 7.3. The ratio of Ru to Rd sets the external OVP threshold.

The resistance values for the resistor divider, can be derived as follows.
First, for the given CDC level, the paralleled resistance of R1 and R2 should be within the range listed in Table 7.1:

$$R_{CDC} = \frac{R_1 \times R_2}{R_1 + R_2} \qquad (7.8)$$

Second, during normal operation the voltage divider, R1 and R2, sets the desired OVP threshold:

$$\left(\frac{N_{AUX}}{N_{SEC}}\right) \times V_{OVP} \times \left(\frac{R_2}{R_2 + R_1}\right) \geq V_{SD-TH(R)} \qquad (7.9)$$

where NAUX is the number of turns for the bias winding, N_{SEC} is the number of turns for the secondary winding, V_{OVP} is the desired OVP tripping point, and $V_{SD-TH(R)}$ is the internal comparator threshold (1.015 V typically) for OVP detection. The combination of Equations (9.6) and (9.7) leads to

$$R_1 = \left(\frac{N_{AUX}}{N_{SEC}}\right) \times R_{CDC} \times \left(\frac{V_{OVP}}{V_{SD-TH(R)}}\right)$$

$$R_2 = \left(\frac{R_1}{R_1 - R_{CDC}}\right) \times R_{CDC} \qquad (7.10)$$

$$R_u = R1;\ R_d = \frac{R_2 * R_{CFG}}{(R_{CFG} - R_2)}; \qquad (7.11)$$

It is recommended the R_{CDC} value is taken as the median value of the resistance range as given in Table7.1, and Ru and Rd can then be readily derived from Equation (7.9).
It should be noted when the CFG pin is used to provide external OVP, an additional constraint will be applied to the resistance range given in Table7.1. Since for the OVP configuration in Figure 7.5, a large negative voltage may occur to the auxiliary winding (V_X in Figure 7.5) during the switch on-time, which can cause a negative current flowing out of the CFG pin. Care needs to be taken to ensure Ru and Rd are large enough, so that the resulting negative current is less than the maximum allowed current, specified in

内部资料

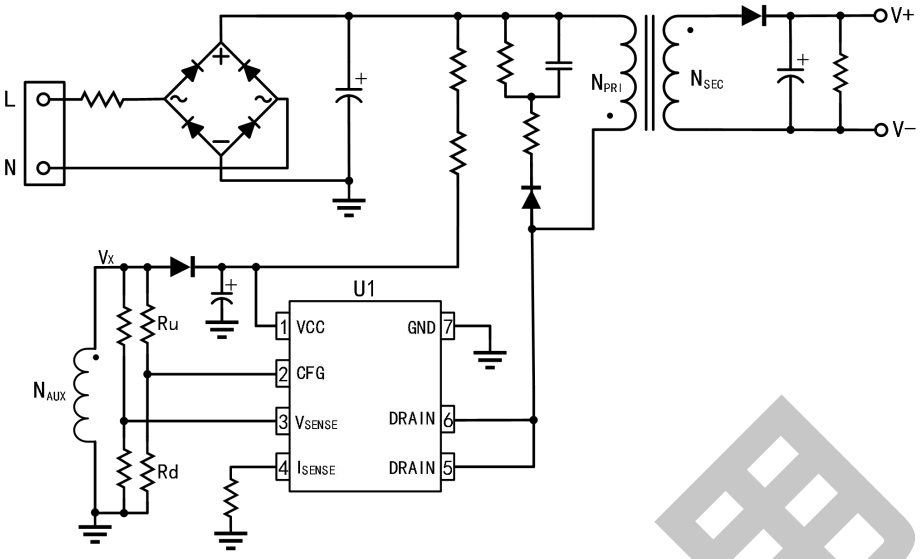
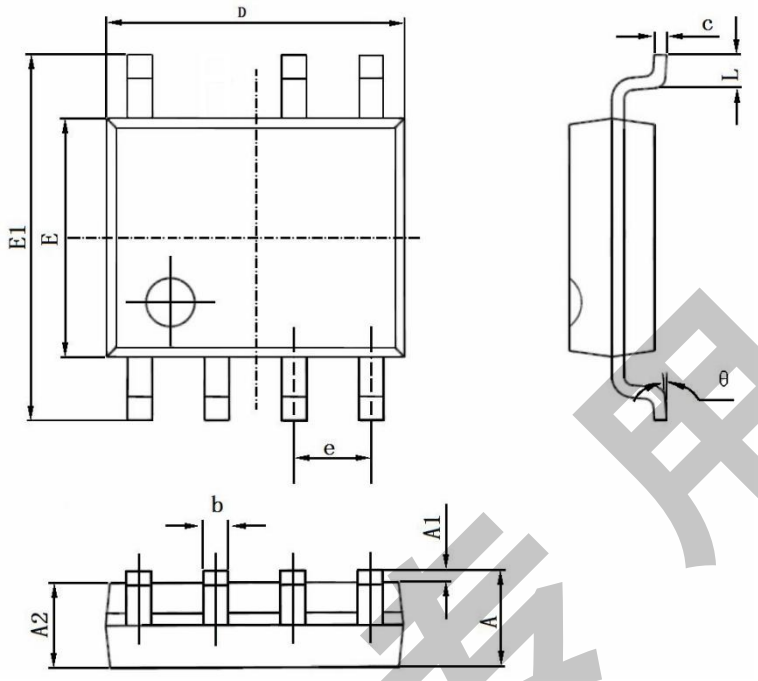


Figure 7.5: G5237FT Typical Application Circuit with CDC,OVP

网站样品

8. Package Information

SOP7 PACKAGE：



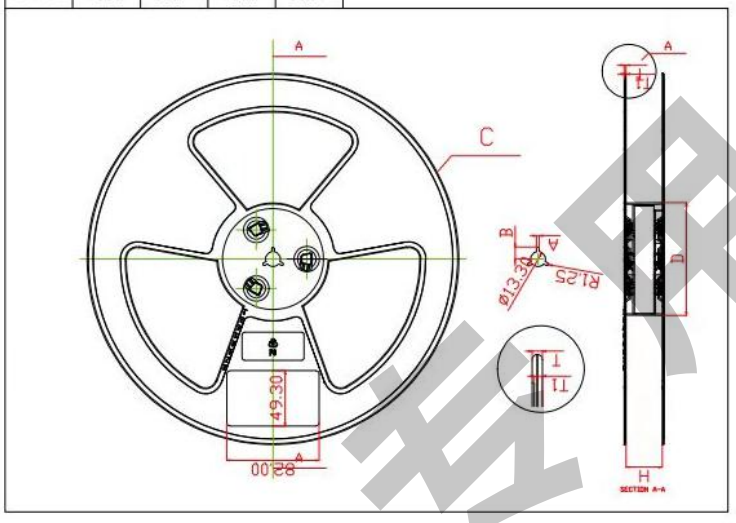
Symbol	Dimension in Millimeters		Dimensions in Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.050	0.250	0.002	0.010
A2	1.250	1.650	0.049	0.065
b	0.310	0.510	0.012	0.020
c	0.100	0.250	0.004	0.010
D	4.700	5.150	0.185	0.203
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

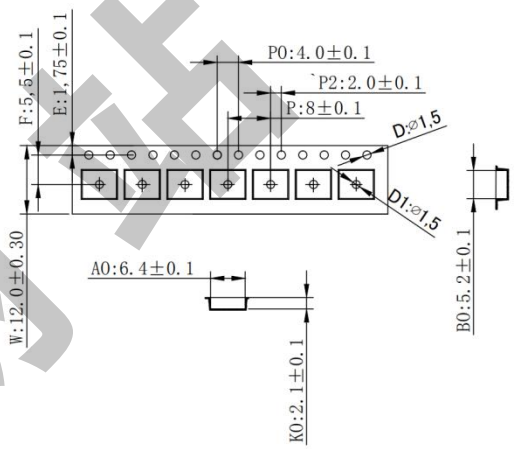
固换前用

9. Tape and Reel Information

Tape and Reel：

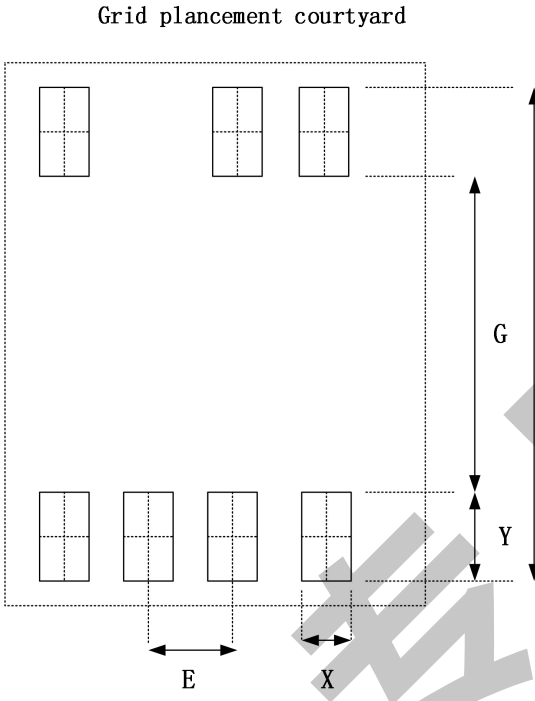
H	12	16	24	32
C±0.2	330	330	330	330
T1±0.2	1.45	1.45	1.45	1.45
B±0.2	10.7	10.7	10.7	10.7
A±0.2	2.5	2.5	2.5	2.5
T±0.2	1.85	1.85	1.85	1.85
D±0.2	100	100	100	100





Unit：mm

10. Suggested pad Layout



Dimensi ous	Z (mm)/(inch)	G (mm)/(inch)	X (mm)/(inch)	Y (mm)/(inch)	E (mm)/(inch)
Value	6.900/0.272	3.900/0.154	0.650/0.026	1.500/0.059	1.270/0.050

IMPORTANT NOTICE

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on GS's Web site.
Global Semiconductor HEADQUARTERS:
Scotia Centre，4th Floor，P.O.Box 2804，George Town， Grand Cayman KY1-1112，Cayman
Visit us at www.globalsemi-group.com for sales contact information.

Addendum：

IR-Reflow Profile For Pb-fre Leads

Pb-free Process – Package Classification Reflow Temperatures

Package Thickness	Tp (°C*)		
<2.5 mm	255 ±10		

* Tolerance: The device manufacturer/supplier shall assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C. For example 260°C+0°C) at the rated MSL level.

Profile Feature	Pb-Free Assembly
Average ramp-up rate (TL to TP)	3°C/second max.
Preheat -Temperature Min (Tsmin) -Temperature Max (Tsmax) -Time (min to max) (ts)	 150°C 200°C 60-180 seconds
Time maintained above: -Temperature (TL) -Time (tL)	 217°C 60-150 seconds
Peak/Classification Temperature (Tp)	See Pb-free Process
Time within 5°C of actual Peak Temperature (tp)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

Notes: All temperatures refer to topside of the package. Measured on the body surface.